General Description

The 843002 is a two output LVPECL synthesizer optimized to generate Fibre Channel reference clock frequencies . Using a 26.5625MHz, 18pF parallel resonant crystal, the following frequencies can be generated based on the 2 frequency select pins (F_SEL[1:0]): 212.5MHz, 187.5MHz, 159.375MHz, 106.25MHz, and 53.125MHz. The 843002 uses IDT's 3rd generation low phase noise VCO technology and can achieve 1ps or lower typical rms phase jitter, easily meeting Fibre Channel jitter requirements. The 843002 is packaged in a small 20-pin TSSOP package.

Features

- Two 3.3V LVPECL outputs
- Selectable crystal oscillator interface or LVCMOS/LVTTL single-ended input
- Supports the following output frequencies: 212.5MHz, 187.5MHz, 159.375MHz, 106.25MHz and 53.125MHz
- VCO range: 560MHz - 680MHz
- RMS phase jitter (637kHz - 10MHz): 0.72ps (typical)
- Typical phase noise at 212.5MHz

  Phase noise:

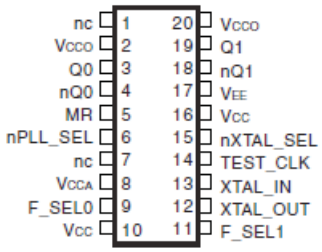
Offset	Noise Power
100Hz	-87.7 dBc/Hz
1KHz	-111.6 dBc/Hz
10KHz	-124.3 dBc/Hz
100KHz	-124.3 dBc/Hz

- Full 3.3V supply mode
- Lead-Free package RoHS compliant
- -30°C to 85°C ambient operating temperature

Frequency Select Function Table

Inputs						Output Frequency (MHz)
Input Frequency (MHz)	F_SEL1	F_SEL0	M Divider Value	N Divider Value	M/N Divider Value	
26.5625	0	0	24	3	8	212.5
26.5625	0	1	24	4	6	159.375
26.5625	1	0	24	6	4	106.25
26.5625	1	1	24	12	2	53.125
23.4375	0	0	24	3	8	187.5

Pin Assignment



843002
20-Lead TSSOP
6.5mm x 4.4mm x 0.92mm package body
G Package
Top View

Block Diagram

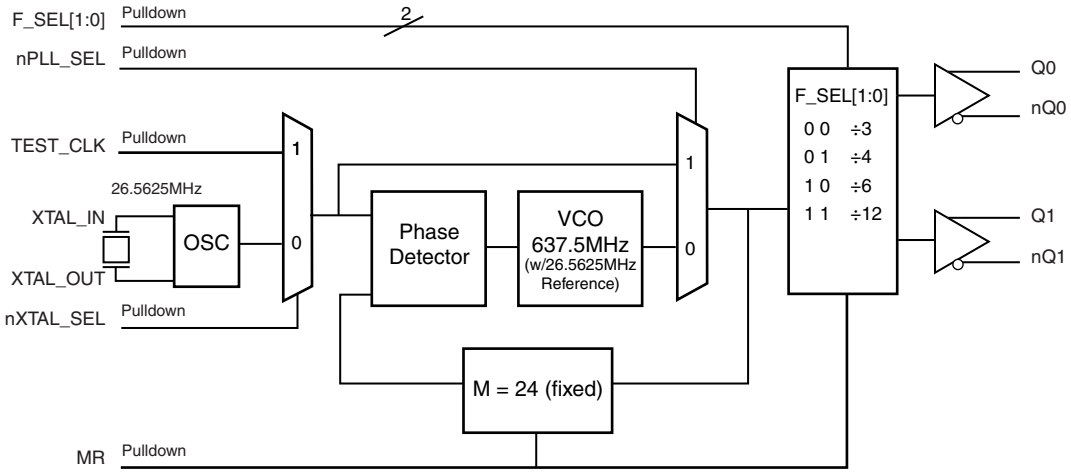


Table 1. Pin Descriptions

Number	Name	Type		Description
1, 7	nc	Unused		No connect.
2, 20	V_{CCO}	Power		Output supply pins.
3, 4	Q0, nQ0	Ouput		Differential output pair. LVPECL interface levels.
5	MR	Input	Pulldown	Active HIGH Master Reset. When logic HIGH, the internal dividers are reset causing the true outputs Qx to go low and the inverted outputs nQx to go high. When logic LOW, the internal dividers and the outputs are enabled. LVCMOS/LVTTL interface levels.
6	nPLL_SEL	Input	Pulldown	Selects between the PLL and TEST_CLK as input to the dividers. When LOW, selects PLL (PLL Enable). When HIGH, deselects the reference clock (PLL Bypass). LVCMOS/LVTTL interface levels.
8	V_{CCA}	Power		Analog supply pin.
9, 11	F_SEL0, F_SEL1	Input	Pulldown	Frequency select pins. LVCMOS/LVTTL interface levels.
10, 16	V_{CC}	Power		Core supply pin.
12, 13	XTAL_OUT, XTAL_IN	Input		Parallel resonant crystal interface. XTAL_OUT is the output, XTAL_IN is the input.
14	TEST_CLK	Input	Pulldown	LVCMOS/LVTTL clock input.
15	nXTAL_SEL	Input	Pulldown	Selects between crystal or TEST_CLK inputs as the the PLL Reference source. Selects XTAL inputs when LOW. Selects TEST_CLK when HIGH. LVCMOS/LVTTL interface levels.
17	V_{EE}	Power		Negative supply pins.
18, 19	nQ1, Q1	Output		Differential output pair. LVPECL interface levels.

NOTE: *Pulldown* refer to internal input resistors. See Table 2, Pin Characteristics, for typical values.

Table 2. Pin Characteristics

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
C_{IN}	Input Capacitance			4		pF
$R_{PULLDOWN}$	Input Pulldown Resistor			51		kΩ

Absolute Maximum Ratings

Supply Voltage, V_{CC}	4.6V
Inputs, V_I	-0.5V to V_{CC} + 0.5V
Outputs, I_O	
Continuous Current	50mA
Surge Current	100mA
Package Thermal Impedance, θ_{JA}	73.2°C/W (0 lfpm)
Storage Temperature, T_{STG}	-65°C to 150°C

NOTE: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics* or *AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

Table 3A. Power Supply DC Characteristics, $V_{CC} = V_{CCA} = V_{CCO}$ = 3.3V±10%, TA = -30°C to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{CC}	Core Supply Voltage		2.97	3.3	3.63	V
V_{CCA}	Analog Supply Voltage		2.97	3.3	3.63	V
V_{CCO}	Output Supply Voltage		2.97	3.3	3.63	V
I_{EE}	Power Supply Current				135	mA
I_{CC}	Core Supply Current				100	mA
I_{CCA}	Analog Supply Current				15	mA
I_{CCO}	Output Supply Current				31	mA

Table 3B. LVCMOS / LVTTL DC Characteristics, $V_{CC} = V_{CCA} = V_{CCO}$ = 3.3V±10%, TA = -30°C to 85°C

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
V_{IH}	Input High Voltage			2		V_{CC} + 0.3	V
V_{IL}	Input Low Voltage	nPLL_SEL, nXTAL_SEL, F_SEL0, F_SEL1, MR		-0.3		0.8	V
		TEST_CLK		-0.3		1.0	V
I_{IH}	Input High Current	TEST_CLK, MR, F_SEL0, F_SEL1, nPLL_SEL, nXTAL_SEL,	$V_{CC} = V_{IN}$ = 3.63V			150	µA
I_{IL}	Input Low Current	TEST_CLK, MR, F_SEL0, F_SEL1, nPLL_SEL, nXTAL_SEL,	V_{CC} = 3.63V, V_{IN} = 0V	-150			µA

Table 3C. LVPECL DC Characteristics, $V_{CC} = V_{CCA} = V_{CCO}$ = 3.3V±10%, TA = -30°C to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{OH}	Output High Voltage; NOTE 1		V_{CCO} - 1.4		V_{CCO} - 0.9	V
V_{OL}	Output Low Voltage; NOTE 1		V_{CCO} - 2.0		V_{CCO} - 1.7	V
V_{SWING}	Peak-to-Peak Output Voltage Swing		0.6		1.0	V

NOTE 1: Outputs terminated with 50Ω to V_{CCO} - 2V.

TABLE 4. CRYSTAL CHARACTERISTICS

Parameter	Test Conditions	Minimum	Typical	Maximum	Units
Mode of Oscillation		Fundamental			
Frequency		23.33	26.5625	28.33	MHz
Equivalent Series Resistance (ESR)				50	Ω
Shunt Capacitance				7	pF

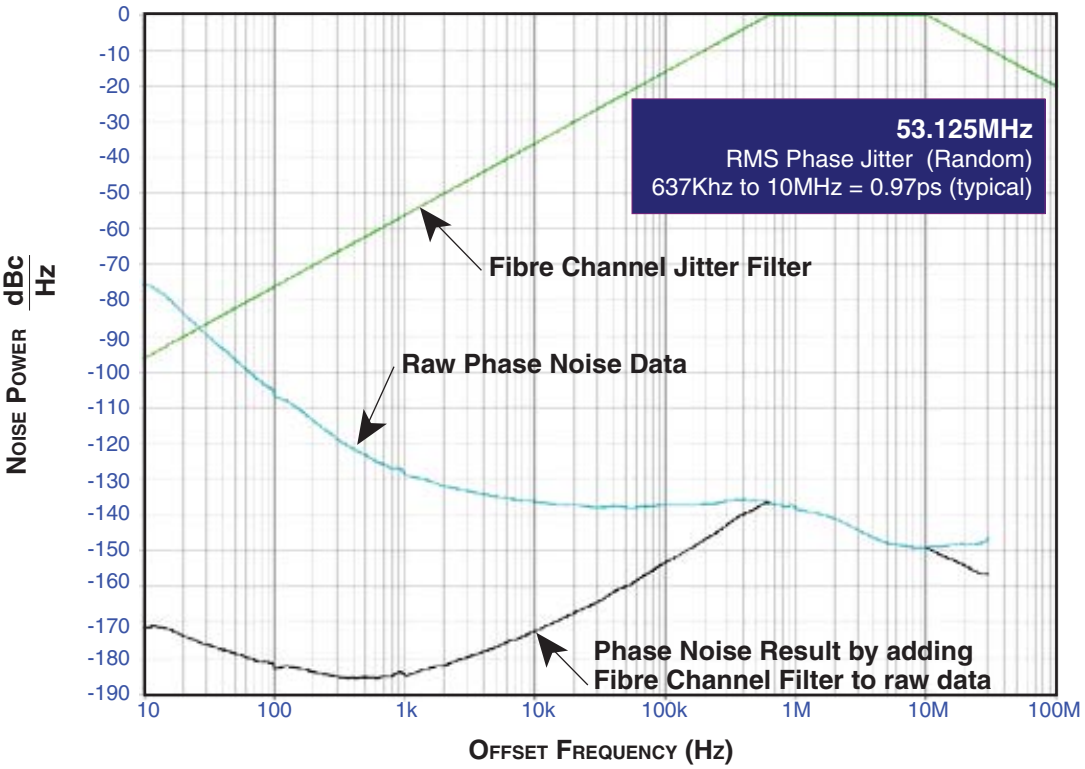
NOTE: Characterized using an 18pF parallel resonant crystal.

TABLE 5. AC CHARACTERISTICS, $V_{CC} = V_{CCA} = V_{CCO}$ = 3.3V±10%, TA = -30°C TO 85°C

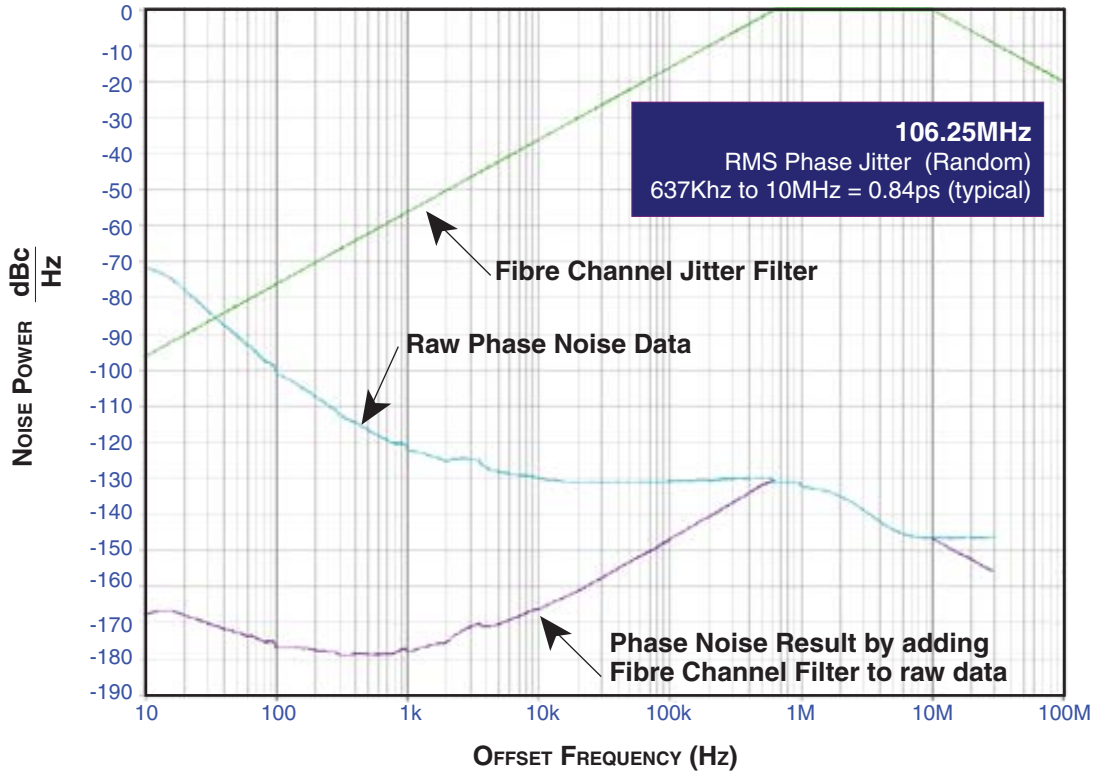
Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f_{OUT}	Output Frequency	F_SEL[1:0] = 00	186.67		226.67	MHz
		F_SEL[1:0] = 01	140		170	MHz
		F_SEL[1:0] = 10	93.33		113.33	MHz
		F_SEL[1:0] =11	46.67		56.67	MHz
tsk(o)	Output Skew; NOTE 1, 2				20	ps
tjit(Ø)	RMS Phase Jitter (Random); NOTE 3	212.5MHz, (637KHz - 10MHz)		0.72		ps
		159.375MHz, (637KHz - 10MHz)		0.76		ps
		106.25MHz, (637KHz - 10MHz)		0.84		ps
		53.125MHz, (637KHz - 10MHz)		0.97		ps
t_R / t_F	Output Rise/Fall Time	20% to 80%	300		600	ps
odc	Output Duty Cycle	F_SEL[1:0] =00	46		54	%
		F_SEL[1:0] ¹ 00	49		51	%

NOTE 1: Defined as skew between outputs at the same supply voltages and with equal load conditions. Measured at $V_{CCO}/2$.
NOTE 2: This parameter is defined in accordance with JEDEC Standard 65.
NOTE 3: See Phase Noise plot.

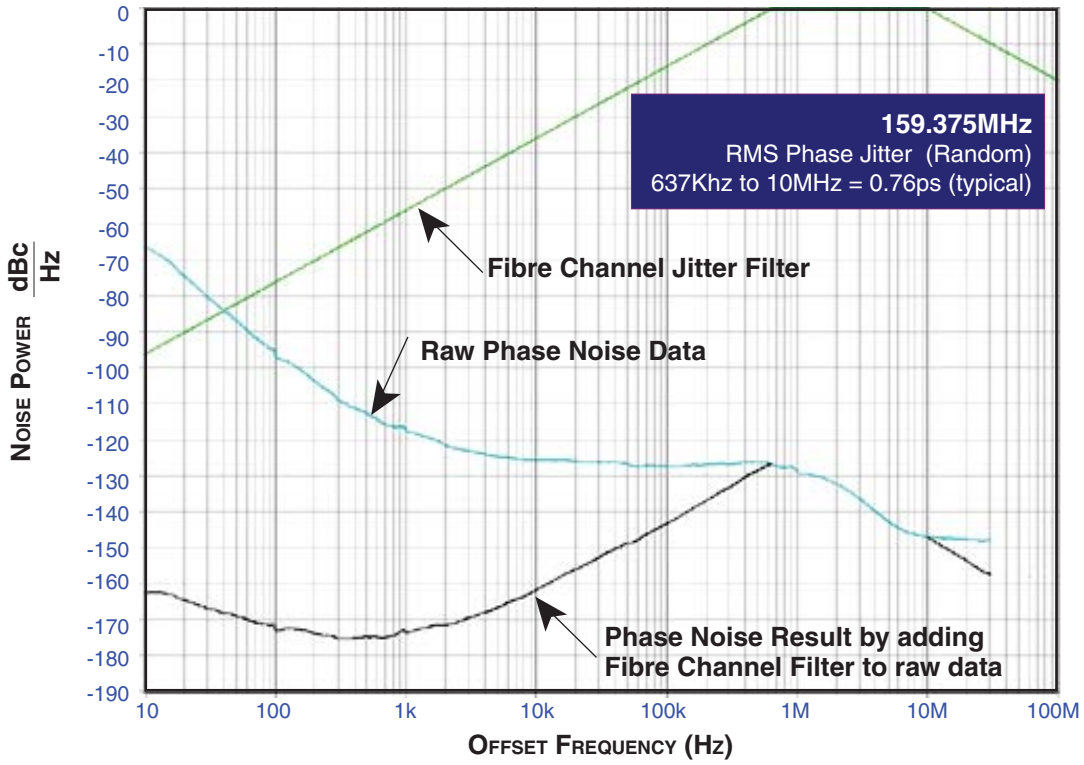
Typical Phase Noise at 53.125MHz



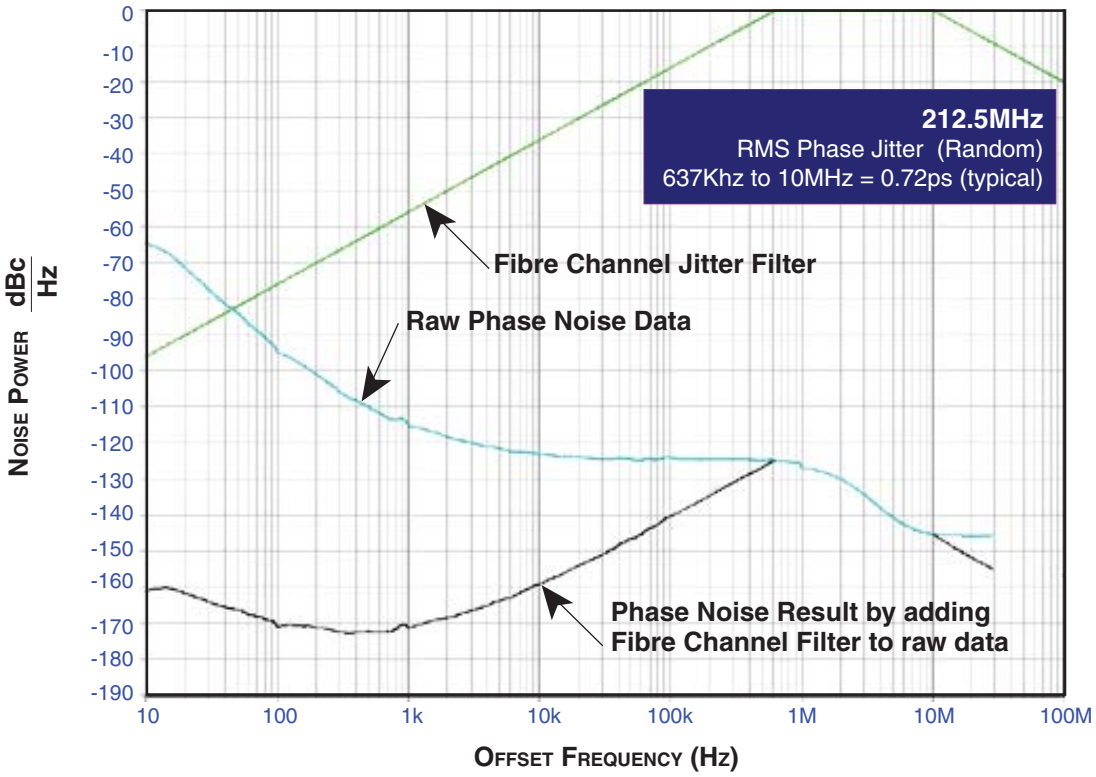
Typical Phase Noise at 106.25MHz



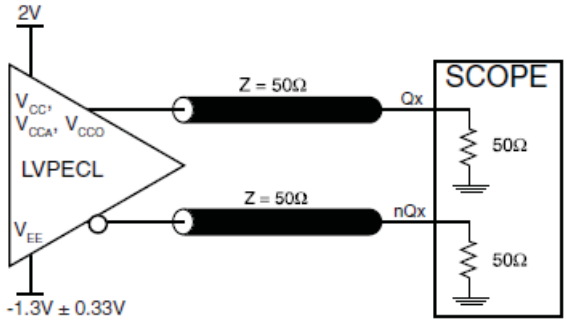
Typical Phase Noise at 159.375MHz



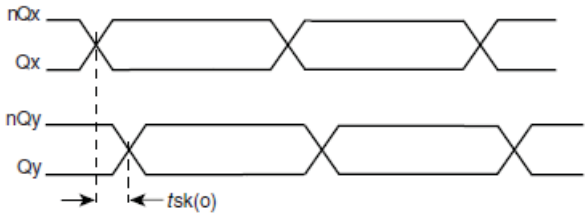
Typical Phase Noise at 212.5MHz



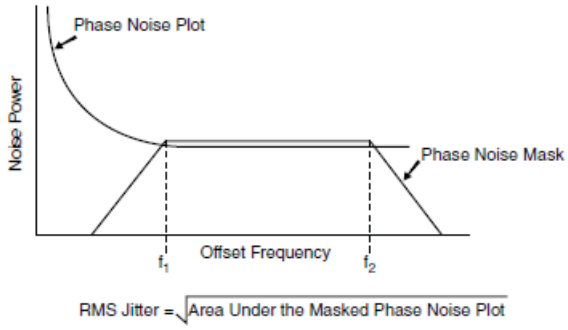
Parameter Measurement Information



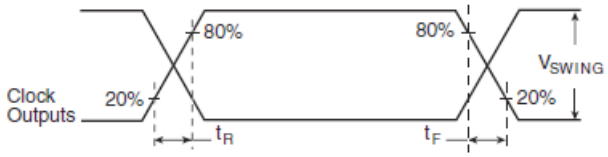
3.3V Core/3.3V Output Load Test Circuit



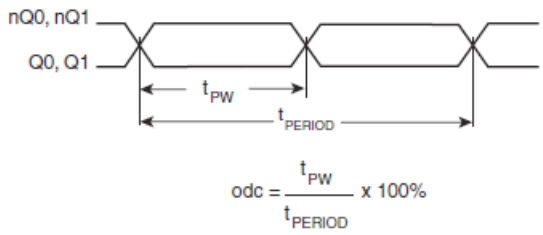
Output Skew



RMS Phase Jitter



Output Rise/Fall Time



Output Duty Cycle/Pulse Width/Period

Applications Information

Power Supply Filtering Techniques

As in any high speed analog circuitry, the power supply pins are vulnerable to random noise. The 843002 provides separate power supplies to isolate any high switching noise from the outputs to the internal PLL. V_{CC}, V_{CCA}, and V_{CCO} should be individually connected to the power supply plane through vias, and bypass capacitors should be used for each pin. To achieve optimum jitter performance, power supply isolation is required. *Figure 1* illustrates how a 10Ω resistor along with a 10µF and a .01µF bypass capacitor should be connected to each V_{CCA}.

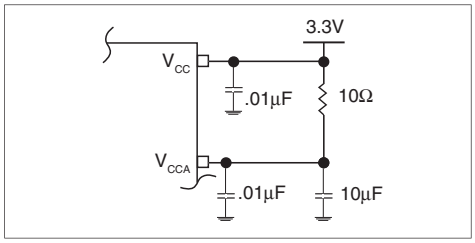


Figure 1. Power Supply Filtering

Termination for 3.3V LVPECL Output

The clock layout topology shown below is a typical termination for LVPECL outputs. The two different layouts mentioned are recommended only as guidelines.

Differential outputs are low impedance follower outputs that generate ECL/LVPECL compatible outputs. Therefore, terminating resistors (DC current path to ground) or current sources must be used for functionality. These outputs are designed to drive 50Ω transmission lines. Matched impedance techniques should be used to maximize operating frequency and minimize signal distortion. *Figures 2A and 2B* show two different layouts which are recommended only as guidelines. Other suitable clock layouts may exist and it would be recommended that the board designers simulate to guarantee compatibility across all printed circuit and clock component process variations.

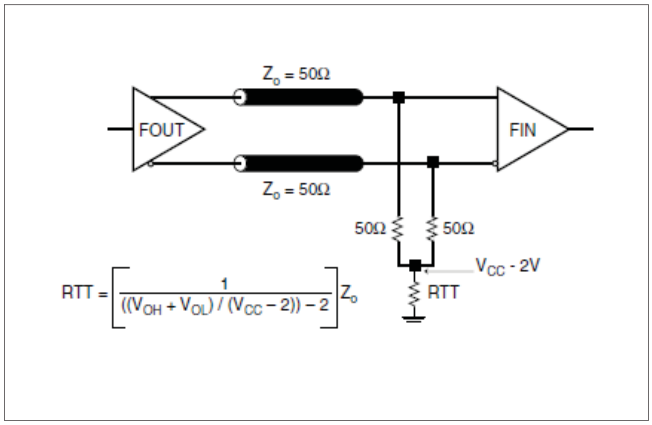


Figure 2A. LVPECL Output Termination

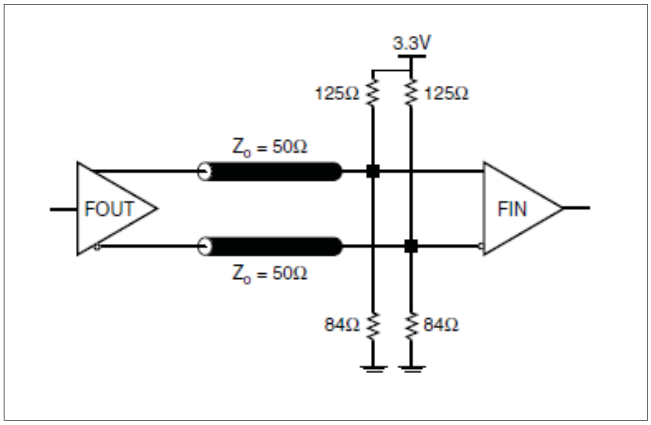


Figure 2B. LVPECL Output Termination

Crystal Input Interface

The 843002 has been characterized with 18pF parallel resonant crystals. The capacitor values shown in *Figure 3* below were determined using a 26.5625MHz 18pF parallel resonant crystal and were chosen to minimize the ppm error.

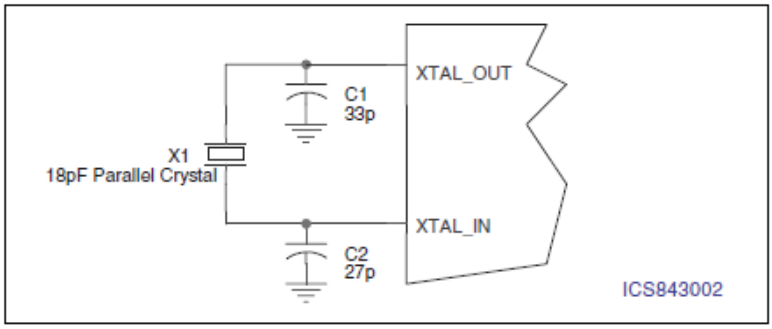


Figure 3. Crystal Input Interface

Layout Guideline

Figure 4A shows a schematic example of the 843002. An example of LVEPCL termination is shown in this schematic. Additional LVPECL termination approaches are shown in the LVPECL Termination Application Note. In this example, an 18 pF parallel resonant 26.5625MHz crystal is used. The C1=27pF and C2=33pF are recommended for frequency accuracy. For different board layout, the C1 and C2 may be slightly adjusted for optimizing frequency accuracy.

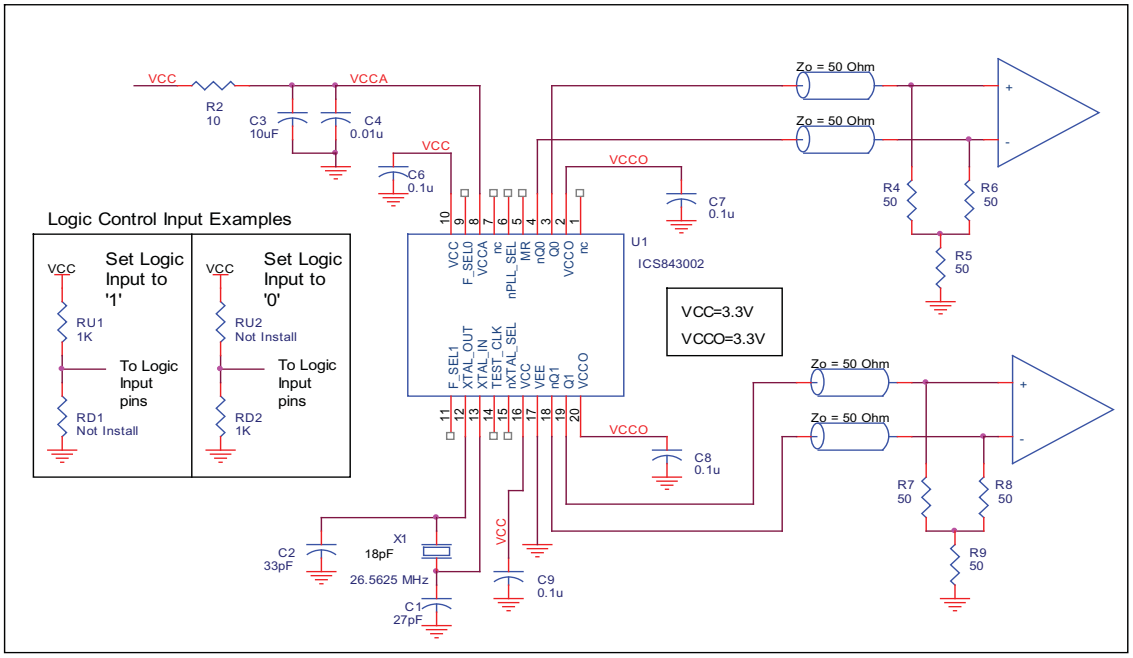


Figure 4A. 843002 Schematic Example

PC Board Layout Example

Figure 4B shows an example of 843002 P.C. board layout. The crystal X1 footprint shown in this example allows installation of either surface mount HC49S or through-hole HC49 package. The footprints of other components in this example are listed in the *Table 6.* There should be at least one decoupling capacitor per power pin. The decoupling capacitors should be located as close as possible to the power pins. The layout assumes that the board has clean analog power ground plane.

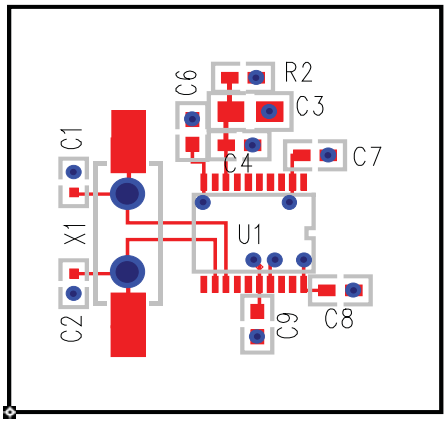


Figure 4B. 843002 PC Board Layout Example

Table 6. Footprint Table

Reference	Size
C1, C2	0402
C3	
C4, C5, C6, C7, C8	
R2	

NOTE: Table 6, lists component sizes shown in this layout example.

Power Considerations

This section provides information on power dissipation and junction temperature for the 843002.
Equations and example calculations are also provided.

1. Power Dissipation.
The total power dissipation for the 843002 is the sum of the core power plus the power dissipated in the load(s).
The following is the power dissipation for V_{CC} = 3.3V + 10% = 3.63V, which gives worst case results.
NOTE: Please refer to Section 3 for details on calculating power dissipated in the load.

- Power (core)$_{MAX}$ = V_{CC_MAX} * I_{EE_MAX} = 3.63V * 135mA = **490mW**
- Power (outputs)$_{MAX}$ = **30mW/Loaded Output pair**
  If all outputs are loaded, the total power is 2 * 30mW = **60mW**

Total Power$_{_MAX}$ (3.63V, with all outputs switching) = 490mW + 60mW = **550mW**

2. Junction Temperature.
JJunction temperature at the junction of the bond wire and bond pad directly affects the reliability of the device. The maximum recommended junction temperature is 125°C. Limiting the internal transistor junction temperature, Tj, to 125°C ensures that the bond wire and bond pad temperature remains below 125°C.

The equation for Tj is as follows: $Tj = \theta_{JA} * Pd_total + T_A$

Tj = Junction Temperature

θ_{JA} = Junction-to-Ambient Thermal Resistance

Pd_total = Total Device Power Dissipation (example calculation is in section 1 above)
T_A = Ambient Temperature

In order to calculate junction temperature, the appropriate junction-to-ambient thermal resistance θ_{JA} must be used. Assuming a moderate air flow of 200 linear feet per minute and a multi-layer board, the appropriate value is 66.6°C/W per Table 7 below.

Therefore, Tj for an ambient temperature of 85°C with all outputs switching is:
85°C + 0.550W * 66.6°C/W = 121.6°C. This is below the limit of 125°C.

This calculation is only an example. Tj will obviously vary depending on the number of loaded outputs, supply voltage, air flow, and the type of board (single layer or multi-layer).

Table 7. Thermal Resistance θ_{JA} for 20-pin TSSOP, Forced Convection

θ_{JA} by Velocity (Linear Feet per Minute)	0	200	500
Single-Layer PCB, JEDEC Standard Test Boards	114.5°C/W	98.0°C/W	88.0°C/W
Multi-Layer PCB, JEDEC Standard Test Boards	73.2°C/W	66.6°C/W	63.5°C/W

NOTE: Most modern PCB designs use multi-layered boards. The data in the second row pertains to most designs.

3. Calculations and Equations.

The purpose of this section is to derive the power dissipated into the load.

LVPECL output driver circuit and termination are shown in *Figure 5.*

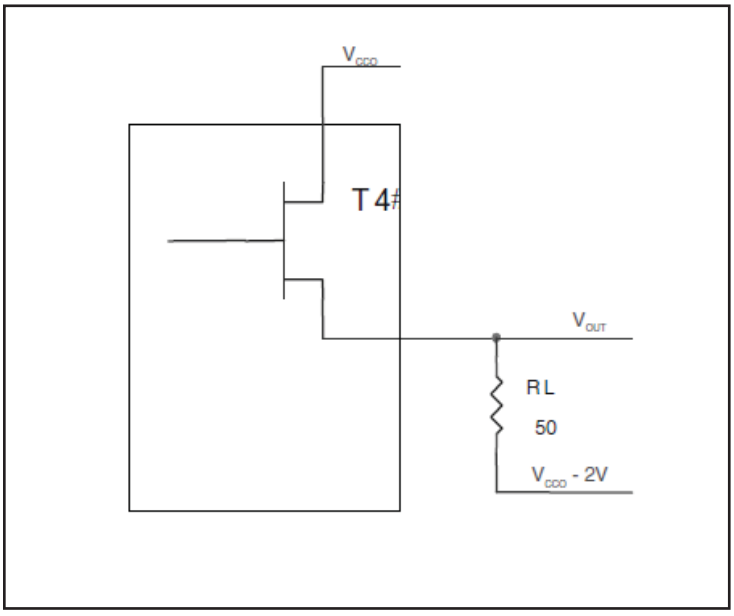


FIGURE 5. LVPECL DRIVER CIRCUIT AND TERMINATION

To calculate worst case power dissipation into the load, use the following equations which assume a 50Ω load, and a termination voltage of V_{CCO} - 2V.

- For logic high, $V_{OUT} = V_{OH_MAX} = \mathbf{V_{CCO_MAX} - 0.9V}$

  $(V_{CCO_MAX} - V_{OH_MAX}) = \mathbf{0.9V}$

- For logic low, $V_{OUT} = V_{OL_MAX} = \mathbf{V_{CCO_MAX} - 1.7V}$

  $(V_{CCO_MAX} - V_{OL_MAX}) = \mathbf{1.7V}$

Pd_H is power dissipation when the output drives high.
Pd_L is the power dissipation when the output drives low.

$Pd_H = [(V_{OH_MAX} – (V_{CCO_MAX} - 2V))/R_L] * (V_{CCO_MAX} - V_{OH_MAX}) = [(2V - (V_{CCO_MAX} - V_{OH_MAX}))/R_L] * (V_{CCO_MAX} - V_{OH_MAX}) =$
$[(2V - 0.9V)/50\Omega] * 0.9V =$ **19.8mW**

$Pd_L = [(V_{OL_MAX} – (V_{CCO_MAX} - 2V))/R_L] * (V_{CCO_MAX} - V_{OL_MAX}) = [(2V - (V_{CCO_MAX} - V_{OL_MAX}))/R_L] * (V_{CCO_MAX} - V_{OL_MAX}) =$
$[(2V - 1.7V)/50\Omega] * 1.7V =$ **10.2mW**

Total Power Dissipation per output pair = Pd_H + Pd_L = **30mW**

Reliability Information

Table 8. θ_{JA} vs. Air Flow Table for 20 Lead TSSOP

θ_{JA} by Velocity (Linear Feet per Minute)			
	0	**200**	**500**
Single-Layer PCB, JEDEC Standard Test Boards	114.5°C/W	98.0°C/W	88.0°C/W
Multi-Layer PCB, JEDEC Standard Test Boards	73.2°C/W	66.6°C/W	63.5°C/W

NOTE: Most modern PCB designs use multi-layered boards. The data in the second row pertains to most designs.

Transistor Count

The transistor count for 843002 is: 2578

Package Outline - G Suffix for 20 Lead TSSOP

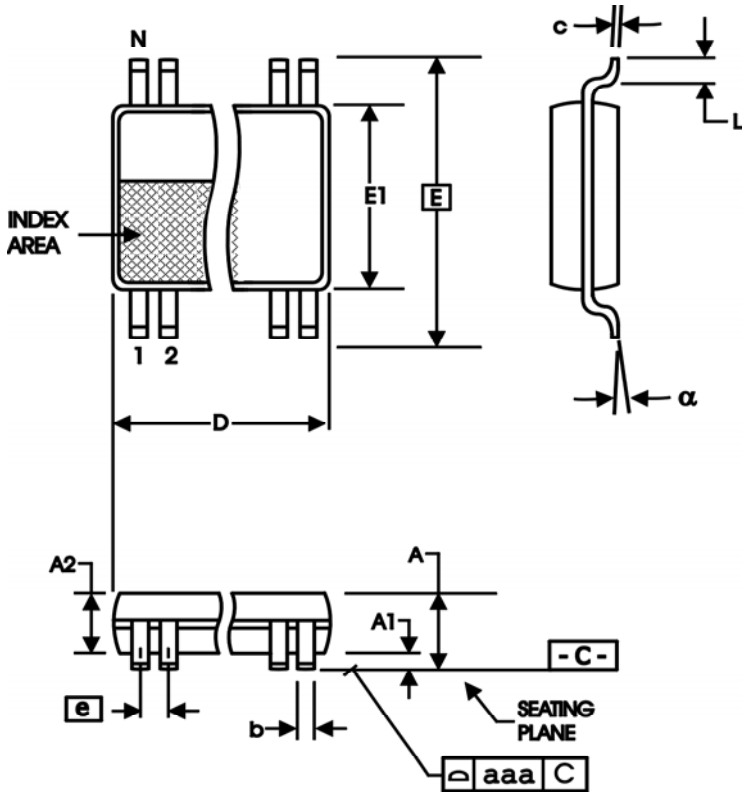


Table 9. Package Dimensions

SYMBOL	Millimeters	
	MIN	MAX
N	20	
A	--	1.20
A1	0.05	0.15
A2	0.80	1.05
b	0.19	0.30
c	0.09	0.20
D	6.40	6.60
E	6.40 BASIC	
E1	4.30	4.50
e	0.65 BASIC	
L	0.45	0.75
α	0°	8°
aaa	--	0.10

Reference Document: JEDEC Publication 95, MO-153

TABLE 10. ORDERING INFORMATION

Part/Order Number	Marking	Package	Shipping Packaging	Temperature
843002AGLF	ICS843002AGL	20 Lead “Lead-Free” TSSOP	tube	-30°C to 85°C
843002AGLFT	ICS843002AGL	20 Lead “Lead-Free” TSSOP	tape & reel	-30°C to 85°C

REVISION HISTORY SHEET				
Rev	**Table**	**Page**	**Description of Change**	**Date**
A		1	Added 187.5MHz to the Frequency Selection Function Table.	8/26/04
A	T10	15	Ordering Information Table - added Lead Free part number.	9/30/04
A	T5	4	AC Characteristics Table - corrected typo, f_{OUT} 180.67 min. to 186.67 min.	12/27/04
A	 T10	1 15	Features section - corrected frequency bullet to read “Supports...output frequencies...” from “...input frequencies...”. Ordering Information Table - updated table.	2/7/05
B	T5	4	AC Characteristics Table - deleted Propagation Delay.	5/6/05
B	T10	14	Ordering Information Table - corrected lead-free marking. Updated Datasheet Header and Footer.	4/17/13
B	T10	1 15	Deleted ICS from part numbers where needed. Corrected part number in the header. Ordering Information - Corrected Package information from 8 Lead TSSOP to 20 Lead TSSOP. Added T to tape and reel part number. Updated header and footer.	1/21/16

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